

# HD74HC393

## Dual 4-bit Binary Counters

REJ03D0625-0200  
 (Previous ADE-205-504)  
 Rev.2.00  
 Mar 30, 2006

### Description

The HD74HC393 contain two 4-bit ripple carry binary counters, which can be cascaded to create a single divide-by-256 counter.

The HD74HC393 is incremented on the high to low transition (negative edge) of the clock input, and each has an independent clear input. When clear is set high all four bits of each counter are set to a low level. This enables count truncation and allows the implementation of divide-by-N counter configurations.

### Features

- High Speed Operation:  $t_{pd}$  (A to  $Q_A$ ) = 16 ns typ ( $C_L$  = 50 pF)
- High Output Current: Fanout of 10 LSTTL Loads
- Wide Operating Voltage:  $V_{CC}$  = 2 to 6 V
- Low Input Current: 1  $\mu$ A max
- Low Quiescent Supply Current:  $I_{CC}$  (static) = 4  $\mu$ A max ( $T_a$  = 25°C)
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74HC393P	DILP-14 pin	PRDP0014AB-B (DP-14AV)	P	—
HD74HC393FPEL	SOP-14 pin (JEITA)	PRSP0014DF-B (FP-14DAV)	FP	EL (2,000 pcs/reel)

Note: Please consult the sales office for the above package availability.

### Function Table

Clock	Clear	Outputs
X	H	L
H	L	No change
L	L	No change
	L	No change
	L	Advance to next state

Note: 1. H; High level, L; Low level, X; Irrelevant



### Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage range	$V_{CC}$	-0.5 to 7.0	V
Input / Output voltage	$V_{IN}, V_{OUT}$	-0.5 to $V_{CC} + 0.5$	V
Input / Output diode current	$I_{IK}, I_{OK}$	$\pm 20$	mA
Output current	$I_{OUT}$	$\pm 25$	mA
$V_{CC}$ , GND current	$I_{CC}$ or $I_{GND}$	$\pm 50$	mA
Power dissipation	$P_T$	500	mW
Storage temperature	$T_{stg}$	-65 to +150	°C

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

### Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	$V_{CC}$	2 to 6	V	
Input / Output voltage	$V_{IN}, V_{OUT}$	0 to $V_{CC}$	V	
Operating temperature	$T_a$	-40 to 85	°C	
Input rise / fall time <sup>*1</sup>	$t_r, t_f$	0 to 1000	ns	$V_{CC} = 2.0\text{ V}$
		0 to 500		$V_{CC} = 4.5\text{ V}$
		0 to 400		$V_{CC} = 6.0\text{ V}$

Note: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

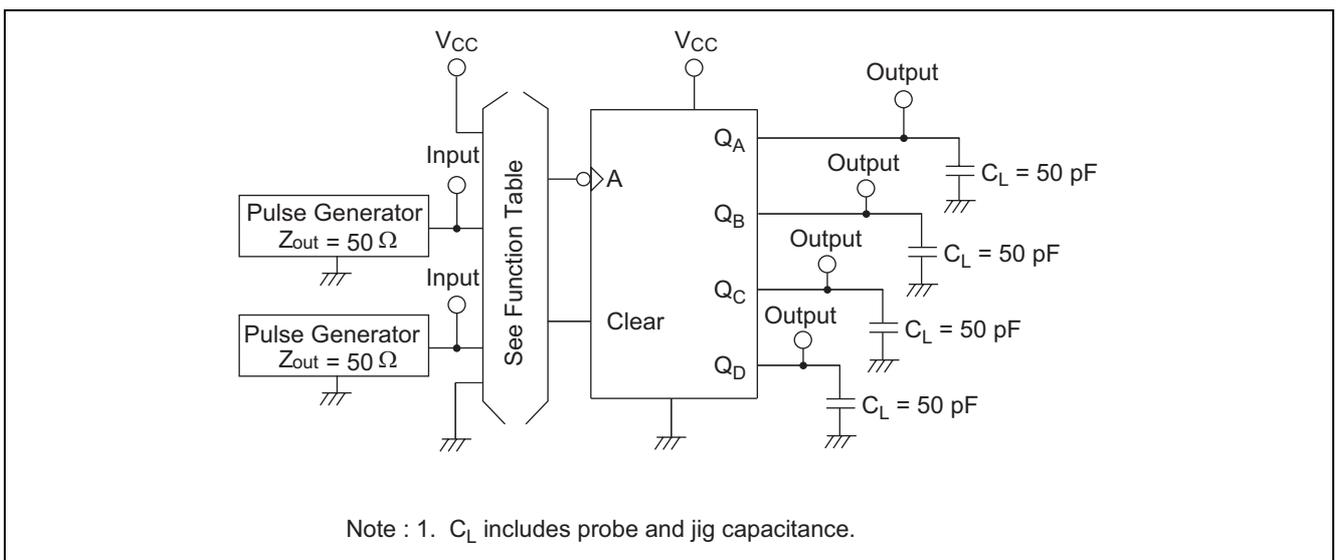
### Electrical Characteristics

Item	Symbol	$V_{CC}$ (V)	$T_a = 25^\circ\text{C}$			$T_a = -40\text{ to }+85^\circ\text{C}$		Unit	Test Conditions	
			Min	Typ	Max	Min	Max			
Input voltage	$V_{IH}$	2.0	1.5	—	—	1.5	—	V		
		4.5	3.15	—	—	3.15	—			
		6.0	4.2	—	—	4.2	—			
	$V_{IL}$	2.0	—	—	0.5	—	0.5	V		
		4.5	—	—	1.35	—	1.35			
		6.0	—	—	1.8	—	1.8			
Output voltage	$V_{OH}$	2.0	1.9	2.0	—	1.9	—	V	$V_{in} = V_{IH}$ or $V_{IL}$	$I_{OH} = -20\ \mu\text{A}$
		4.5	4.4	4.5	—	4.4	—			$I_{OH} = -4\ \text{mA}$
		6.0	5.9	6.0	—	5.9	—			$I_{OH} = -5.2\ \text{mA}$
		4.5	4.18	—	—	4.13	—			
		6.0	5.68	—	—	5.63	—			
	$V_{OL}$	2.0	—	0.0	0.1	—	0.1	V	$V_{in} = V_{IH}$ or $V_{IL}$	$I_{OL} = 20\ \mu\text{A}$
		4.5	—	0.0	0.1	—	0.1			
		6.0	—	0.0	0.1	—	0.1			
		4.5	—	—	0.26	—	0.33			$I_{OH} = 4\ \text{mA}$
		6.0	—	—	0.26	—	0.33			$I_{OH} = 5.2\ \text{mA}$
Input current	$I_{in}$	6.0	—	—	$\pm 0.1$	—	$\pm 1.0$	$\mu\text{A}$	$V_{in} = V_{CC}$ or GND	
Quiescent supply current	$I_{CC}$	6.0	—	—	4.0	—	40	$\mu\text{A}$	$V_{in} = V_{CC}$ or GND, $I_{out} = 0\ \mu\text{A}$	

Switching Characteristics ( $C_L = 50 \text{ pF}$ , Input  $t_r = t_f = 6 \text{ ns}$ )

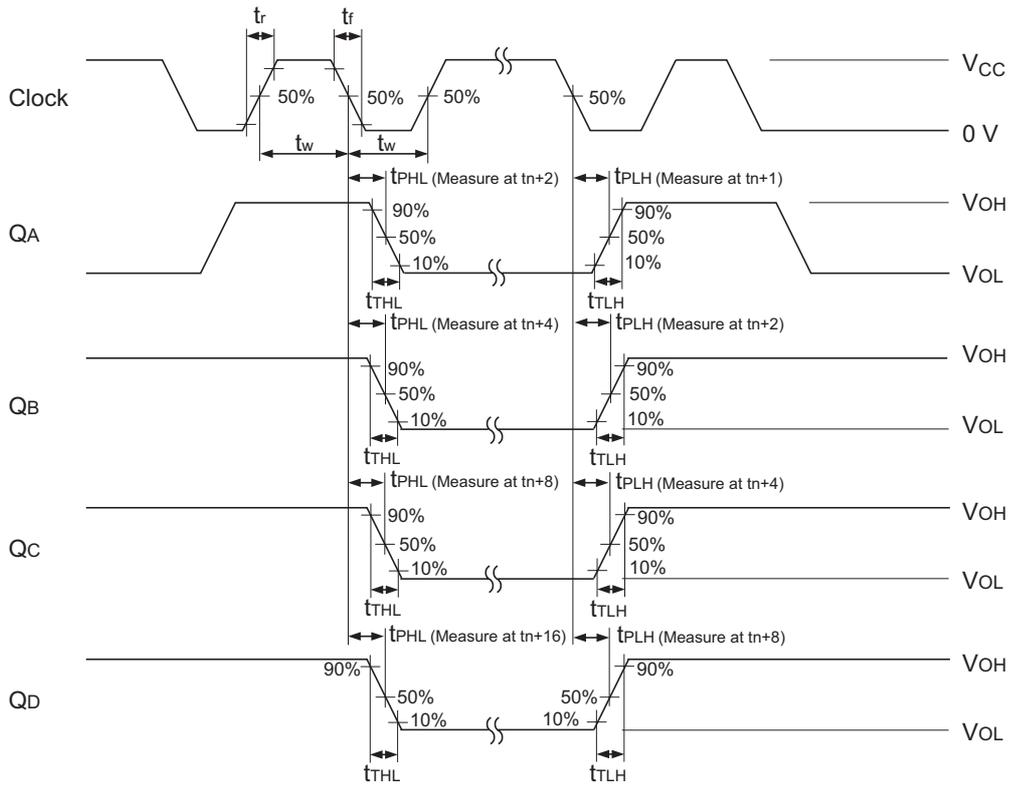
Item	Symbol	$V_{CC}$ (V)	$T_a = 25^\circ\text{C}$			$T_a = -40 \text{ to } +85^\circ\text{C}$		Unit	Test Conditions
			Min	Typ	Max	Min	Max		
Maximum clock frequency	$f_{max}$	2.0	—	—	5	—	4	MHz	
		4.5	—	—	25	—	20		
		6.0	—	—	29	—	24		
Propagation delay time	$t_{PLH}$	2.0	—	—	120	—	150	ns	Clock to $Q_A$
		4.5	—	16	24	—	30		
		6.0	—	—	20	—	26		
	$t_{PHL}$	2.0	—	—	185	—	230	ns	Clock to $Q_B$
		4.5	—	20	37	—	46		
		6.0	—	—	31	—	39		
	$t_{PLH}$	2.0	—	—	220	—	275	ns	Clock to $Q_C$
		4.5	—	24	44	—	55		
		6.0	—	—	37	—	47		
	$t_{PHL}$	2.0	—	—	260	—	325	ns	Clock to $Q_D$
		4.5	—	28	52	—	65		
		6.0	—	—	44	—	55		
$t_{PHL}$	2.0	—	—	150	—	190	ns	Clear to $Q_A, Q_B, Q_C, Q_D$	
	4.5	—	21	30	—	38			
	6.0	—	—	28	—	33			
Pulse width	$t_w$	2.0	80	—	—	100	—	ns	Clock, clear
		4.5	16	—	—	20	—		
		6.0	14	—	—	17	—		
Removal time	$t_h$	2.0	50	—	—	65	—	ns	Clear to clock
		4.5	10	—	—	13	—		
		6.0	9	—	—	11	—		
Output rise/fall time	$t_{TLH}$ $t_{THL}$	2.0	—	—	75	—	95	ns	
		4.5	—	5	15	—	19		
		6.0	—	—	13	—	16		
Input capacitance	$C_{in}$	—	—	5	10	—	10	pF	

Test Circuit



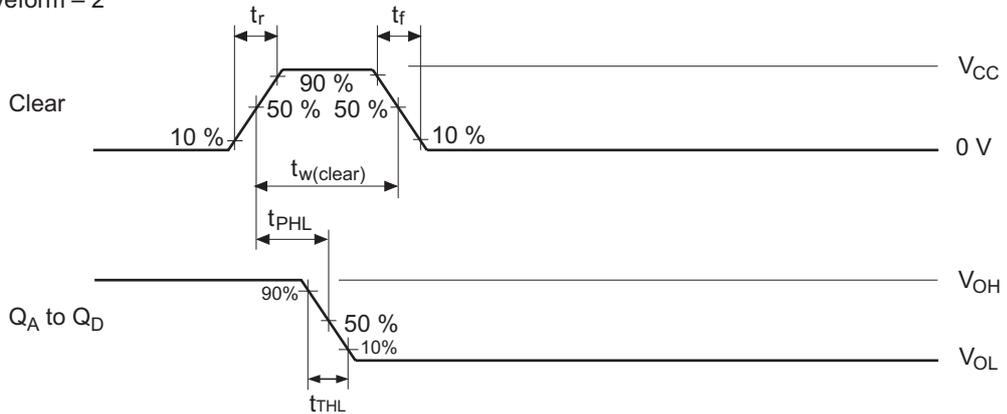
Waveforms

• Waveform – 1



- Notes: 1. Input waveform:  $PRR \leq 1 \text{ MHz}$ ,  $Z_o = 50 \Omega$ ,  $t_r \leq 6 \text{ ns}$ ,  $t_f \leq 6 \text{ ns}$
- 2.  $t_n$  is bit time with all outputs at low.

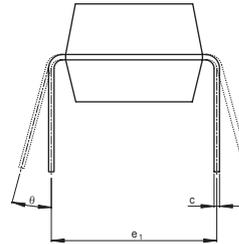
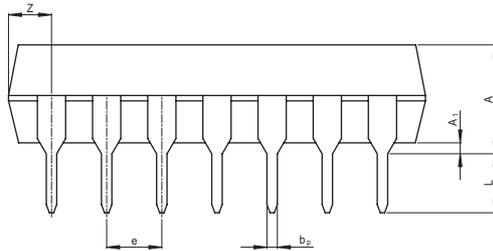
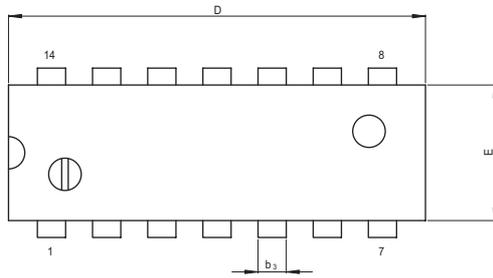
• Waveform – 2



- Notes: 1. Input waveform:  $PRR \leq 1 \text{ MHz}$ ,  $Z_o = 50 \Omega$ ,  $t_r \leq 6 \text{ ns}$ ,  $t_f \leq 6 \text{ ns}$
- 2. The output are measured one at a time with one transition per measurement.

Package Dimensions

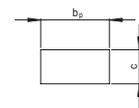
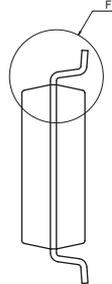
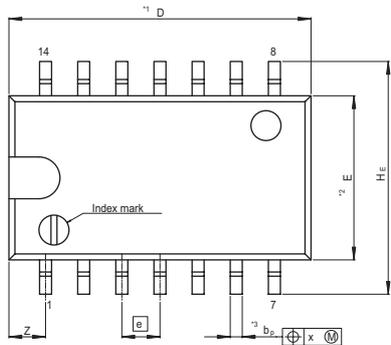
JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
P-DIP14-6.3x19.2-2.54	PRDP0014AB-B	DP-14AV	0.97g



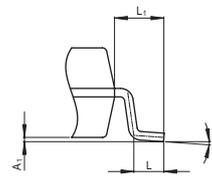
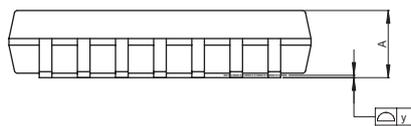
(Ni/Pd/Au plating)

Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
e <sub>1</sub>	—	7.62	—
D	—	19.2	20.32
E	—	6.3	7.4
A	—	—	5.06
A <sub>1</sub>	0.51	—	—
b <sub>p</sub>	0.40	0.48	0.56
b <sub>3</sub>	—	1.30	—
c	0.19	0.25	0.31
θ	0°	—	15°
e	2.29	2.54	2.79
Z	—	—	2.39
L	2.54	—	—

JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
P-SOP14-5.5x10.06-1.27	PRSP0014DF-B	FP-14DAV	0.23g



Terminal cross section (Ni/Pd/Au plating)



Detail F

NOTE)  
 1. DIMENSIONS\*\*1 (Nom)\*AND\*\*2\* DO NOT INCLUDE MOLD FLASH.  
 2. DIMENSION\*\*3\*DOES NOT INCLUDE TRIM OFFSET.

Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	—	10.06	10.5
E	—	5.50	—
A <sub>2</sub>	—	—	—
A <sub>1</sub>	0.00	0.10	0.20
A	—	—	2.20
b <sub>p</sub>	0.34	0.40	0.46
b <sub>1</sub>	—	—	—
c	0.15	0.20	0.25
c <sub>1</sub>	—	—	—
θ	0°	—	8°
H <sub>E</sub>	7.50	7.80	8.00
Ⓧ	—	1.27	—
x	—	—	0.12
y	—	—	0.15
Z	—	—	1.42
L	0.50	0.70	0.90
L <sub>1</sub>	—	1.15	—

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